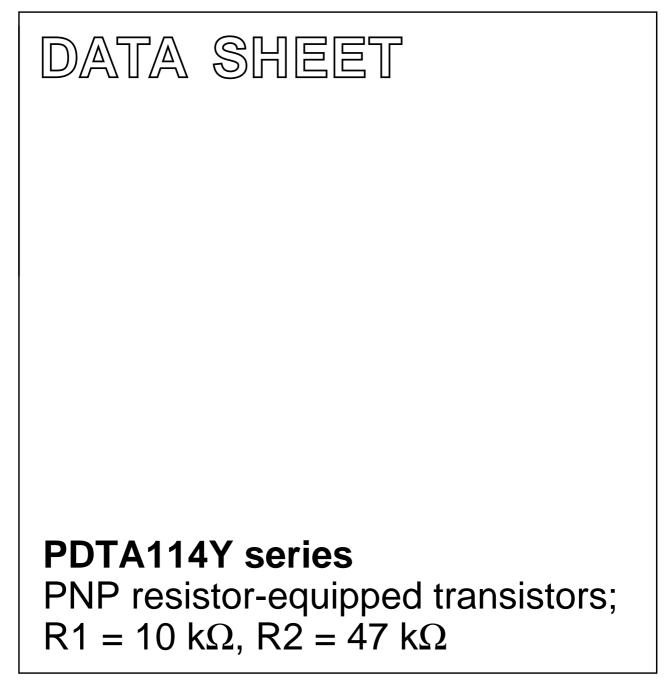
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2003 Sep 09 2004 Aug 02



PDTA114Y series

FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

PRODUCT OVERVIEW

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	-50	V
lo	output current (DC)	-	-100	mA
R1	bias resistor	10	_	kΩ
R2	bias resistor	47	_	kΩ

DESCRIPTION

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

TYPE NUMBER	PACKAGE			NPN COMPLEMENT	
	PHILIPS	EIAJ	MARKING CODE		
PDTA114YE	SOT416	SC-75	36	PDTC114YE	
PDTA114YEF	SOT490	SC-89	37	PDTC114YEF	
PDTA114YK	SOT346	SC-59	54	PDTC114YK	
PDTA114YM	SOT883	SC-101	DF	PDTC114YM	
PDTA114YS	SOT54 (TO-92)	SC-43	TA114Y	PDTC114YS	
PDTA114YT	SOT23	_	*29 ⁽¹⁾	PDTC114YT	
PDTA114YU	SOT323	SC-70	*55 ⁽¹⁾	PDTC114YU	

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PDTA114Y series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTA114YS	$ \begin{array}{c} \hline 1 \\ 2 \\ \hline 3 \\ \hline \\ MAM338 \end{array} $	PIN 1 2 3	DESCRIPTION base collector emitter		
PDTA114YE PDTA114YEF PDTA114YK PDTA114YT PDTA114YU	$ \begin{array}{c} 3 \\ 1 \\ 1 \\ Top view \end{array} $	1 2 3	base emitter collector		
PDTA114YM	2 1 Bottom view Bottom view MDB267	1 2 3	base emitter collector		

PDTA114Y series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	IBOL PARAMETER CONDITIONS		MIN.	MAX.	UNIT	
V _{CBO}	collector-base voltage	open emitter	_	-50	V	
V _{CEO}	collector-emitter voltage	open base	-	-50	V	
V _{EBO}	emitter-base voltage	open collector	-	-10	V	
VI	input voltage					
	positive		_	+6	V	
	negative		_	-40	V	
I _O	output current (DC)		-	-100	mA	
I _{CM}	peak collector current		-	-100	mA	
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$				
	SOT54	note 1	_	500	mW	
	SOT23	note 1	_	250	mW	
	SOT346	note 1	_	250	mW	
	SOT323	note 1	_	200	mW	
	SOT490	notes 1 and 2	_	250	mW	
	SOT883	notes 2 and 3	_	250	mW	
	SOT416	note 1	_	150	mW	
T _{stg}	storage temperature		-65	+150	°C	
Tj	junction temperature		-	150	°C	
T _{amb}	operating ambient temperature		-65	+150	°C	

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 µm copper strip line.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	note 1	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

PDTA114Y series

CHARACTERISTICS

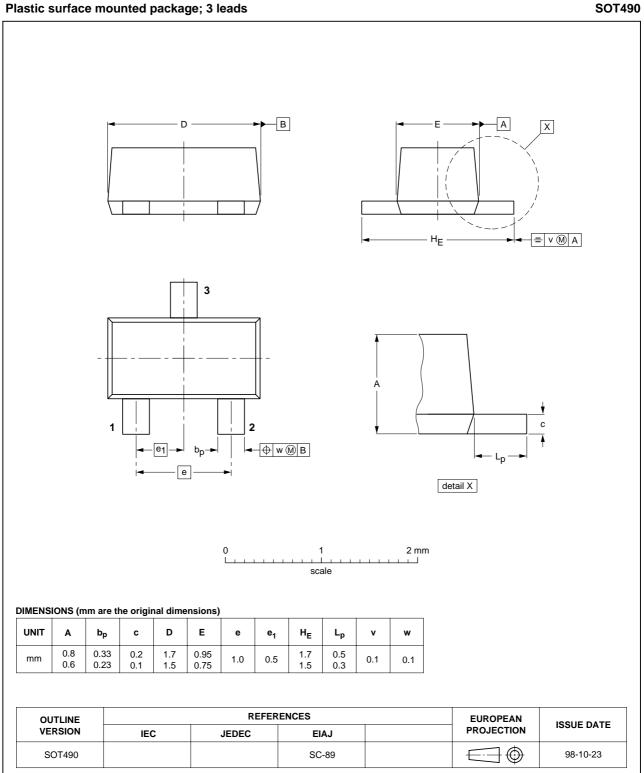
 T_{amb} = 25 °C unless otherwise specified.

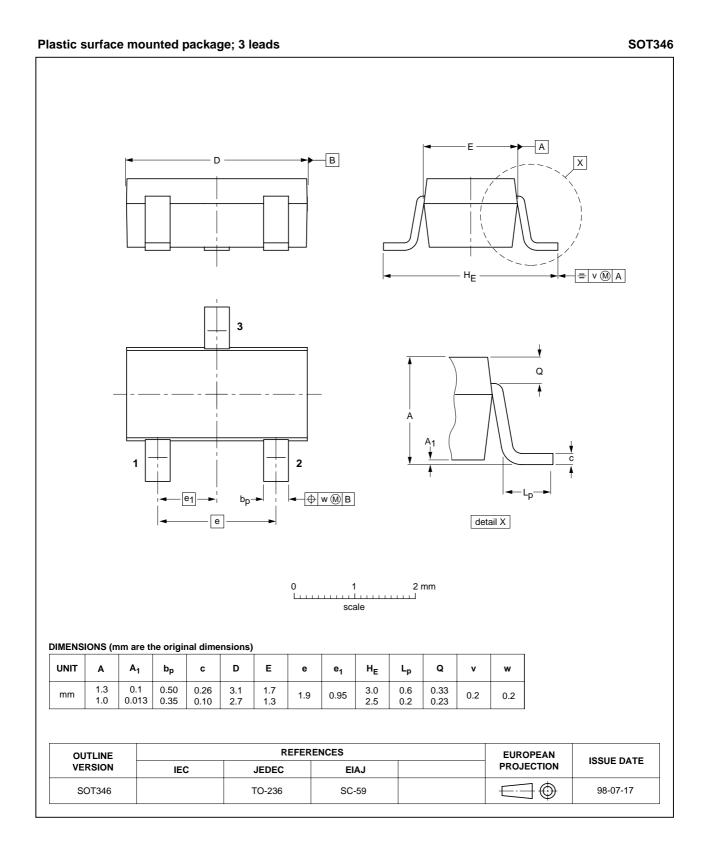
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0$	_	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0$	_	-	-1	μA
		$V_{CE} = -30 \text{ V}; I_B = 0; T_j = 150 ^{\circ}\text{C}$	-	-	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0$	—	-	-150	μA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -5$ mA; $I_{\rm B} = -0.25$ mA	_	-	-100	mV
V _{i(off)}	input-off voltage	$I_{C} = -100 \ \mu\text{A}; \ V_{CE} = -5 \ V$	_	-0.7	-0.5	V
V _{i(on)}	input-on voltage	$I_{C} = -1 \text{ mA}; V_{CE} = -0.3 \text{ V}$	-1.4	-0.8	-	V
R1	input resistor		7	10	13	kΩ
R2 R1	resistor ratio		3.7	4.7	5.7	
C _c	collector capacitance	ctor capacitance $I_E = i_e = 0; V_{CB} = -10 V; f = 1 MHz$		-	3	pF

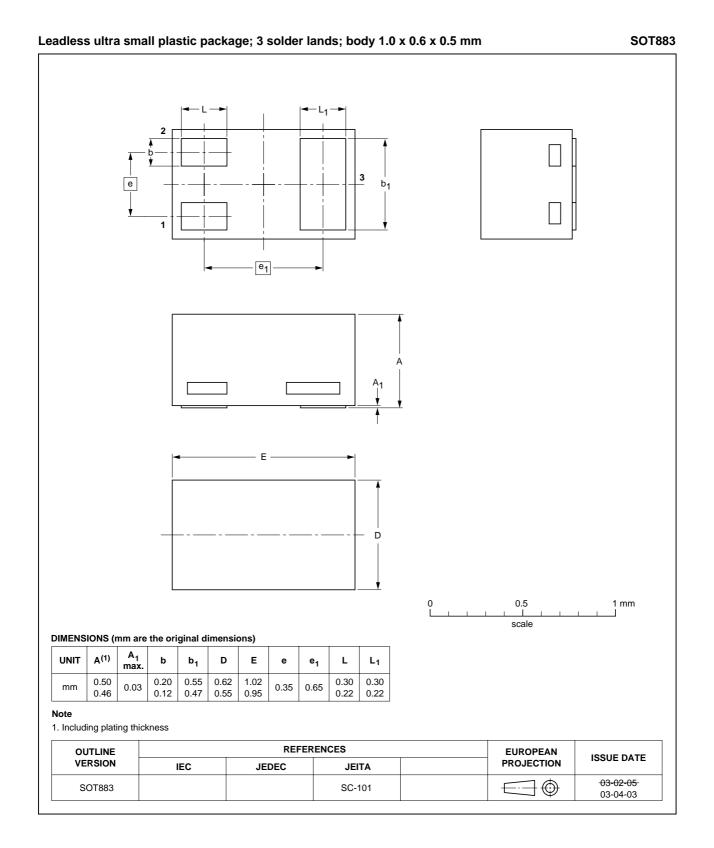
PDTA114Y series

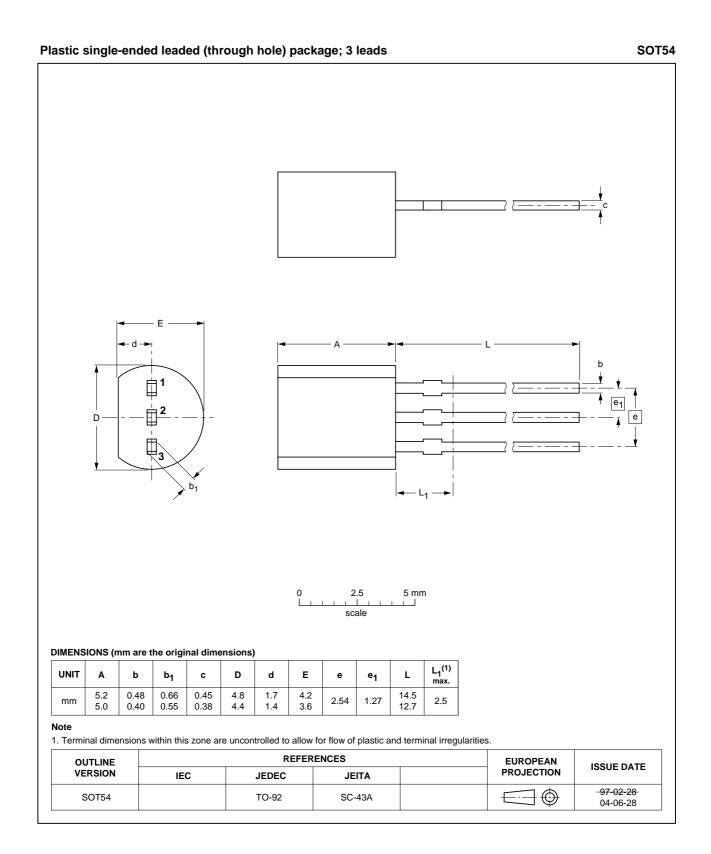
PNP resistor-equipped transistors; $R1 = 10 \text{ k}\Omega$, $R2 = 47 \text{ k}\Omega$

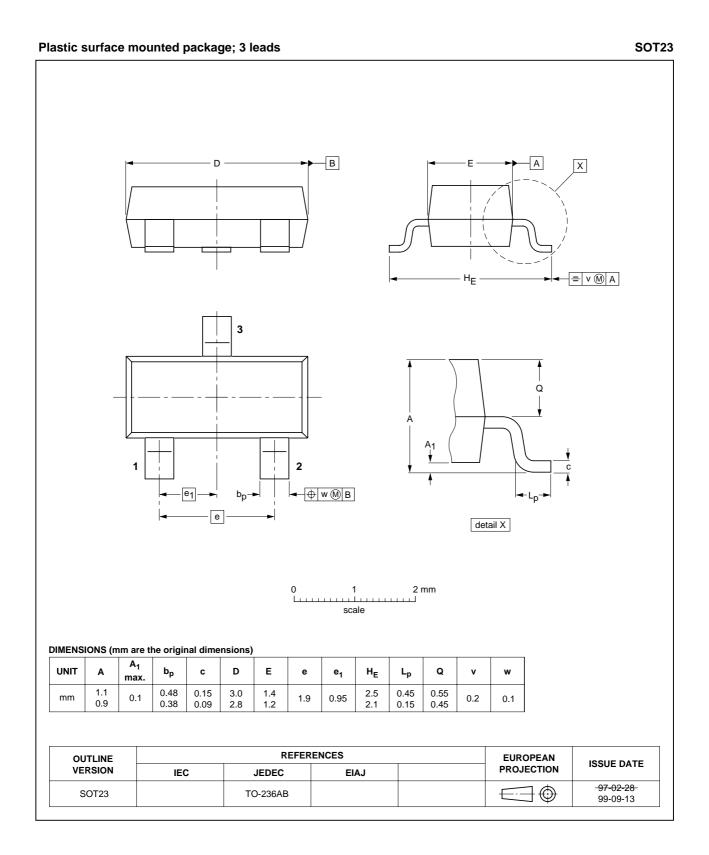
PACKAGE OUTLINES

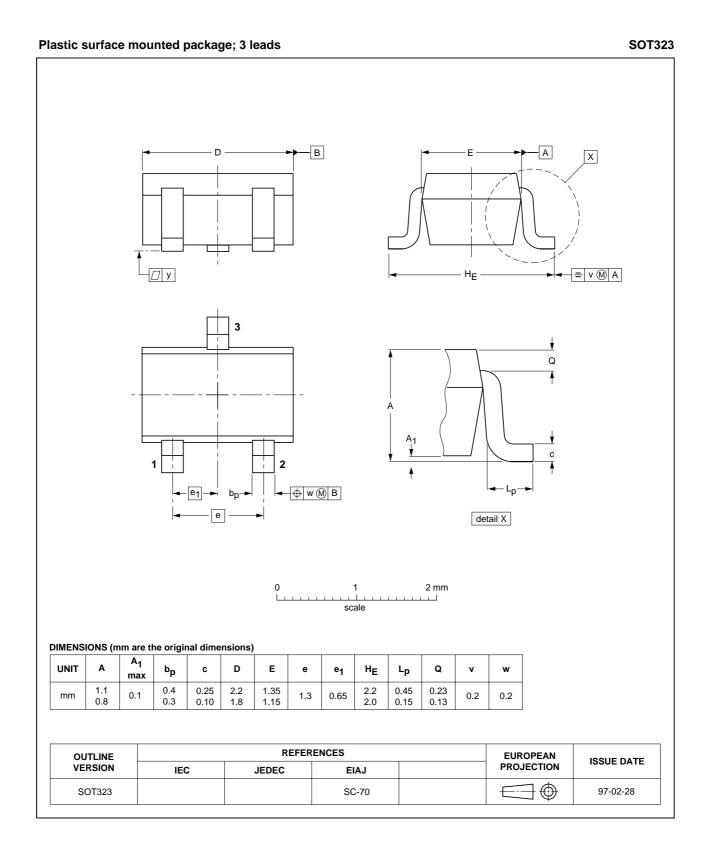


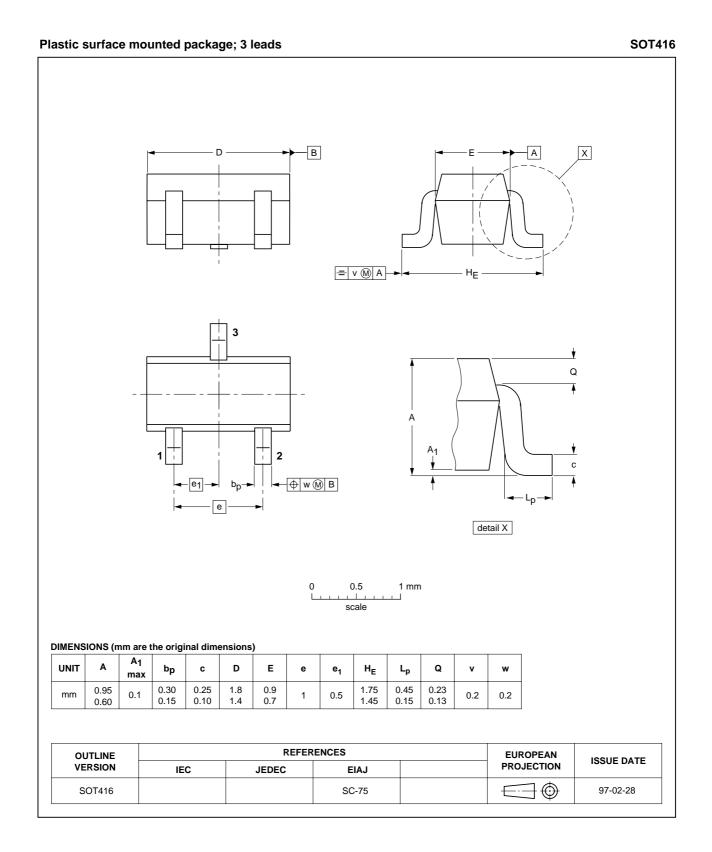












PDTA114Y series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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